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Real-Space Imaging of the Tailored Plasmons in Twisted Bilayer Graphene

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Abstract

We report a systematic plasmonic study of twisted bilayer graphene (tBLG) – two graphene layers stacked with a twist angle. Through real-space nanoimaging of tBLG single crystals with a wide distribution of twist angles, we find that tBLG supports confined infrared plasmons that are sensitively dependent on the twist angle. At small twist angles, tBLG has a plasmon wavelength comparable to that of single-layer graphene (SLG). At larger twist angles, the plasmon wavelength of tBLG increases significantly with apparently lower damping. Further analysis and modeling indicate that the observed twist-angle-dependence of tBLG plasmons in the Dirac linear regime is mainly due to the Fermi-velocity renormalization, a direct consequence of interlayer electronic coupling. Our work unveils the tailored plasmonic characteristics of tBLG and deepens our understanding of the intriguing nano-optical physics in novel van der Waals (vdW) coupled two-dimensional (2D) materials.

Main text

Graphene Dirac plasmons [1-6], which are collective oscillations of Dirac fermions in graphene, have been widely investigated in recent years by using both the electron energy loss spectroscopy [7-9] and optical imaging/spectroscopy [10-21] techniques. These quasiparticles demonstrate many superior characteristics including high confinement, long lifetime, strong field enhancement, broad spectral range, electrical tunability and a broad spectral range from terahertz to infrared [1-21]. So far, plasmons in single layer graphene (SLG) have been extensively studied and are generally well understood. One convenient way to create new plasmonic materials with novel physics and properties is by stacking graphene and other 2D materials into vdW materials or heterostructures. Indeed, the 2D nature of graphene makes it extremely sensitive to interlayer coupling that could dramatically modify the properties of Dirac fermions and their plasmonic excitations. For example, earlier studies about Bernal-stacked BLG [20,22] and graphene/hBN heterostructures [23,24] have demonstrated many unique plasmonic characteristics compared to those of SLG.

In this Letter, we report a systematic nano-infrared imaging study of plasmons in tBLG [Fig. 1(a)], which is formed when two misorientated graphene layers are stacked together by vdW forces. Depending on the twist angle (θ) between the two graphene layers, moiré patterns

with different periodicities could form [Fig. 1(b)]. Due to the interlayer coupling and modulation of Dirac fermions by moiré superlattice potential, the electronic structure of tBLG shows distinct features compared to SLG and Bernal-stacked BLG, and it varies systematically with θ . For example, tBLG with a sizable θ features two separated Dirac cones [Fig. 1(c)] in the momentum space [25-34]. Moreover, the Fermi velocity (v_F^{tBLG}) close to the charge neutrality point is renormalized compared to that of SLG (v_F^{SLG}), namely v_F^{tBLG} drops systematically below v_F^{SLG} as θ decreases [25-30]. Therefore, tBLG is a unique system where the Fermi velocity of Dirac fermions could become an adjustable variable in experimental studies. The unique electronic properties of tBLG have led to observations of many interesting optical phenomena through far-field spectroscopic experiments [35-38]. So far, plasmonic responses of tBLG have not been explored experimentally despite the potential rich physics according to theoretical predictions [39,40].

Here we utilize a scattering-type scanning near-field optical microscope (s-SNOM) to perform nano-infrared imaging studies of tBLG plasmons. The s-SNOM apparatus is built based on an atomic force microscope (AFM). As illustrated in Fig. 1(a), the infrared light (solid arrow) from a continuous-wave infrared laser is focused at the apex of a metalized AFM tip. The laser-illuminated tip acts as both a launcher and a detector of surface plasmons [13-23]. The back-scattered light (dashed arrow) off the tip-sample system contains essential information about plasmons underneath the tip. The s-SNOM collects simultaneously the topography, near-field scattering amplitude (s) and phase (ψ). By analyzing both the s and ψ data images, we can determine the key plasmonic parameters of tBLG. Our samples were grown by the chemical vapor deposition (CVD) method on copper foils [41-43] and then transferred to the standard SiO_2/Si substrates (Supplemental Material [44]). As shown in Fig. 1(d), both SLG and tBLG are single-crystal grains with a hexagonal shape and the tBLG grains are typically located at the center of relatively larger SLG grains. Occasionally, we also see hexagon-like shapes with slightly curved edges (Fig. S5) [45,46], but in all cases, these SLG or tBLG single-crystals demonstrate a six-fold rotational symmetry (Supplemental Material [44]). According to the previous studies [45,47], the six-fold flake symmetry correlates strictly and accurately with the lattice orientation, so it is convenient to determine the twist angle with a relatively good accuracy ($\pm 1^\circ$) by comparing the orientations of the tBLG and SLG grains.

Representative s-SNOM imaging data are shown in Fig. 2, where we plot both the normalized amplitude [Fig. 2(b)] and phase [Fig. 2(c)] signals of a typical sample region containing two tBLG grains. The data images were taken at an excitation laser energy of $E = 0.11$ eV that is away from the strong optical phonon resonance of SiO_2 centered at about 0.14 eV [13]. Therefore, the near-field responses of graphene at our excitation energy are mainly due to plasmons [14]. Figure 2(a) sketches the sample configuration, where we can conveniently determine the twist angles of tBLG from the orientations of the hexagonal grains. For example, the tBLG sample labeled as ‘tBLG1’ has a twist angle of about 26° relative to SLG and the one labeled as ‘tBLG2’ has a twist angle close to 1° . Their different twist angles result in distinct near-field responses. As shown in Figs. 2(b) and 2(c), tBLG1 has significant higher near-field amplitude compared to SLG but shows no clear phase contrast with respect to the latter. On the contrary, the amplitude of tBLG2 is almost the same as that of SLG and its phase is slightly weaker. Such dramatic differences in the near-field responses are clear indications of the strong θ dependence of tBLG. More near-field data images are given in Figs. S1 and S2, where additional tBLG samples with various twist angles are shown. In all the samples we measured (partly

shown in Figs. 2, S1 and S2), the near-field amplitude of tBLG is comparable to SLG for $\theta \leq 3^\circ$, and gradually increases from an intermediate signal ($\theta \approx 5^\circ$) to a maximum value ($\theta > 7^\circ$). The phase signal of tBLG, on the other hand, is roughly the same as SLG for $\theta > 7^\circ$, but slightly declines as θ approaches 0° . The above θ dependence is more clearly seen in Figs. 4(c) and 4(d), where we summarized the extracted amplitude and phase signal data points (squares) from tens of tBLG samples that we measured.

The unique near-field responses discussed above are directly linked to the plasmons in tBLG. Indeed, we found direct evidence of plasmons in the high-resolution imaging data (Figs. 3 and S3) taken over five small sample regions (marked with dashed squares) in Fig. S1. These regions (labeled with ‘P1’ – ‘P5’) are chosen to be at the edge of SLG or the boundaries between SLG and tBLG. The amplitude images are shown in Figs. 3(a) – 3(e), where we observe bright fringe(s) close to the SLG edge and the SLG/tBLG boundaries. This can be seen more clearly in the line profiles [grey solid curves in Fig. 3(f) – 3(j)] taken perpendicular to the edges or boundaries in the amplitude images (along blue dashed lines). Here in these line profiles, the peak features correspond to the bright fringes in the images.

According to previous studies [14-24], the bright fringes registered by the s-SNOM are generated due to the constructive interference between tip-launched and edge- or boundary-reflected plasmons. The plasmonic origin of the observed fringes is further confirmed by the spectroscopic imaging data (Fig. S4), where we observed a systematic evolution of the bright fringes with laser energy, consistent with the dispersion nature of plasmons. There are two main observations from these plasmonic fringes data (Fig. 3). First, fringes are clear and strong close to the SLG/tBLG3 ($\theta \approx 27^\circ$) and SLG/tBLG4 ($\theta \approx 12^\circ$) boundaries. As θ decreases, the fringes become weaker and fewer at the SLG/tBLG5 ($\theta \approx 5^\circ$) boundary and then barely seen at the SLG/tBLG6 boundary ($\theta \approx 3^\circ$). Second, in the case of SLG/tBLG3 [Fig. 3(b)] and SLG/tBLG4 [Fig. 3(c)] boundaries, we can easily identify two to three fringes. Nevertheless, at the edge of SLG [Fig. 3(a)], we can only see one bright fringe. Note that the edge of SLG is a nearly-perfect plasmon reflector. The plasmon reflection at the SLG/tBLG boundaries, on the other hand, is in principle weaker. Therefore, we can tell directly from the fringes data that our SLG sample has a relatively higher plasmon damping compared to tBLG with relatively large θ . Figure S3 plot the near-field phase images and the corresponding line profiles, where plasmonic interference fringes are also seen. The amplitude and phase imaging data are consistent and complementary to each other. They are all considered in our modeling as discussed in detail below.

To extract quantitative information about plasmons in SLG and tBLG, we performed numerical modeling of both the plasmonic fringes profiles (Figs. 3 and S3) and the θ -dependent near-field amplitude and phase signals [Figs. 4(c) and 4(d)] by using the so-called spheroid model. In this model, the s-SNOM tip is approximated as a highly-elongated conducting spheroid (Fig. S7) and we evaluate the complex scattering signal by computing the total radiating dipole of the coupled tip-sample system (Supplemental Material [44]). We wish to emphasize that our model has been proven to effective in describing s-SNOM responses of graphene with quantitative accuracy [14,16,23]. The main modeling parameter of the sample is the optical conductivity ($\sigma = \sigma_1 + i\sigma_2$) that is directly linked to the complex plasmon wavevector ($q_p = q_1 + iq_2$) under the long-wavelength approximation:

$$q_p \approx i\varepsilon_0(1 + \varepsilon_s)E/\hbar\sigma. \quad (1)$$

Here \hbar is the reduced plank constant, ε_0 is the vacuum permittivity, and ε_s is the relative permittivity of SiO₂. For convenience, our analysis and discussions are based on the following

two parameters: the plasmon wavelength ($\lambda_p = 2\pi/q_1$) and damping rate ($\gamma_p = q_2/q_1$). Based on Eq. 1, we know that the plasmon wavelength (λ_p) is roughly proportional to σ_2 , and the damping rate (γ_p) scales linearly with σ_1/σ_2 .

We first fit the plasmonic fringe profiles of SLG [Figs. 3(f) and S3(f)]. Through the fitting, we extract the plasmon wavelength (λ_p^{SLG}) and damping rate (γ_p^{SLG}) of SLG at $E = 0.11$ eV to be about 279 nm and 0.2, respectively. Based on Eq. (1), we can establish a simple relation between λ_p^{SLG} and the carrier density (n) under the Drude approximation:

$$\lambda_p^{\text{SLG}} \approx \frac{2e^2 \hbar v_F^{\text{SLG}} \sqrt{\pi |n|}}{(\epsilon_1 + \epsilon_2) \epsilon_0 E^2}. \quad (2)$$

Here $v_F^{\text{SLG}} \approx 10^6$ m/s is the Fermi velocity of SLG. Equation (2) allows us to estimate the carrier density of SLG to be $n \approx 1.2 \times 10^{13} \text{ cm}^{-2}$, which is a typical value for highly-hole-doped CVD samples on SiO_2/Si substrates at ambient conditions [16]. The relatively high doping is mainly due to the impurities on the surface of SiO_2 as well as the water and oxygen molecules in the air [48]. Considering that all the samples studied here share the same substrate and atmospheric conditions, they are expected to share roughly an equal density of external dopants and therefore a similar carrier density [21,22].

Based on the extracted parameters of SLG, we then determine both the plasmon wavelength (λ_p^{tBLG}) and damping rate (γ_p^{tBLG}) of tBLG by fitting the fringe profiles at the SLG/tBLG boundaries (Figs. 3 and S3). Through fitting, we estimate that (λ_p^{tBLG} , γ_p^{tBLG}) of tBLG3 ($\theta \approx 27^\circ$), tBLG4 ($\theta \approx 12^\circ$), tBLG5 ($\theta \approx 5^\circ$) and tBLG6 ($\theta \approx 3^\circ$) to be (393 nm, 0.10), (387 nm, 0.11), (340 nm, 0.16) and (278 nm, 0.28), respectively. These numbers are plotted in Figs. 4(a) and 4(b) as data points. Note that the first two numbers of λ_p^{tBLG} can be read out directly from the fringe profiles of tBLG3 and tBLG4 by doubling the fringe period [arrows in Figs. 3(g) and 3(h)]. Nevertheless, precise modeling of the complex fringe profiles is required to extract both λ_p^{tBLG} and γ_p^{tBLG} , and to analyze data from tBLG samples without strong fringes [Figs. 3(d) and 3(e)]. In the latter case, the modeling fits mainly the s and ψ signals of tBLG in contrast to SLG. In Figs. 4(a) and 4(b), we show the modeling curve of s and ψ contrast signals of tBLG versus SLG at a wide distribution of twist angles (red curves), which match well the trend of the experimental data points with twist angles above 3° (marked with dashed lines). At twist angles below 3° , the experimental data points clearly deviate from the modeling curve, which will be discussed in the following paragraphs. The smooth $\lambda_p^{\text{tBLG}}(\theta)$ and $\gamma_p^{\text{tBLG}}(\theta)$ parameters [red curves in Figs. 4(a) and 4(b)] used to model the s and ψ contrast signals are fully consistent with the discrete data points obtained from fringe profile fitting.

Now we wish to discuss the origin of the θ -dependence of λ_p^{tBLG} and γ_p^{tBLG} . We first pay attention to twist angles above 3° , where tBLG is in the Dirac regime [Fig. 1(c)] [25–29]. Here we assume that carriers are equally distributed among the two graphene layers, which is reasonable considering no external gating. The general results won't change much even with slightly unequal carrier distribution among the two graphene layers (Fig. S6 and Supplemental Material [44]). Under the equal carrier distribution assumption, λ_p^{tBLG} can be written as

$$\lambda_p^{\text{tBLG}}(\theta) \approx \frac{2e^2\hbar\sqrt{2\pi|n|}}{(\epsilon_1 + \epsilon_2)\epsilon_0 E^2} v_F^{\text{tBLG}}(\theta), \quad (3)$$

where the Fermi velocity of tBLG (v_F^{tBLG}) is proven to be sensitively dependent on θ due to the Fermi velocity renormalization. The amount of Fermi velocity renormalization is determined by the interlayer coupling energy (t) of tBLG [inset of Fig. 4(a)] as described by the following equation: [25]

$$v_F^{\text{tBLG}}(\theta) = v_F^{\text{SLG}} \left[1 - 9 \left(\frac{t}{\hbar v_F^{\text{SLG}} \Delta K} \right) \right]. \quad (4)$$

Here, $\Delta K = (8\pi/3a)\sin(\theta/2)$ is the momentum separation of the two Dirac cones [Fig. 1(c)], and $a = 0.346$ nm is the lattice constant. Equation 4 indicates that t is the one single parameter that controls $v_F^{\text{tBLG}}(\theta)$ and hence $\lambda_p^{\text{tBLG}}(\theta)$. Here we set t to be 0.1 eV, which is consistent with previous studies [29,34]. With such a t setting, we calculated $\lambda_p^{\text{tBLG}}(\theta)$ based on Eqs. (3) and (4), which is shown as the red curve in Fig. 4(a). Other choices of t will lead to either faster or slower decreasing of v_F^{tBLG} and hence λ_p^{tBLG} as θ drops [inset of Fig. 4(a)].

The origin for the higher γ_p^{tBLG} at smaller θ in the Dirac regime ($\theta \geq 3^\circ$) is likely due to the stronger charge scattering rates [49,50]. According to previous literature [51], the charge scattering rates (Γ) due to either long-range Coulomb scattering or short-range defect scattering are inverse proportional to the Fermi velocity. Therefore, as θ decreases, Γ rises and thus γ_p^{tBLG} increases. Note that interband transitions are forbidden due to the Pauli blocking for $\theta \geq 3^\circ$, where threshold energy for interband transitions ($2E_F^{\text{tBLG}}$) is estimated to be over 0.2 eV, far above our laser energy (0.11 eV).

Finally, we wish to discuss briefly tBLG samples with twist angles below 3° , where the Dirac approximation begins to fail [26-29]. In this regime, we find that the amplitude signal of the tBLG samples deviates from the projected trend of the modeling curves and stay close to that of SLG [Fig. 4(c)]. With quantitative modeling (Fig. S8), we estimate that the λ_p^{tBLG} at small twist angles ($\theta \leq 2^\circ$) is in the range from 279 to 314 nm. According to previous theoretical studies [26-28], the lowest-energy bands of the tBLG with small twist angles become flat or nearly-flat close to the charge neutrality point, which could lead to an extremely small λ_p^{tBLG} (Eq. 3). The finite λ_p^{tBLG} of tBLG ($\theta \leq 2^\circ$) observed here suggests that the Fermi surface of our highly-doped samples is away from these relatively flat bands. The phase signals [Fig. 4(d)] of tBLG ($\theta \leq 2^\circ$) appear to be slightly smaller than that of SLG and large-twist-angle tBLG, indicating even higher plasmon damping rates: $\gamma_p^{\text{tBLG}}(\theta \leq 2^\circ) = 0.2 - 0.4$ (Fig. S8). The higher damping is most likely due to interband transitions, which are enabled in tBLG ($\theta \leq 2^\circ$) at our excitation energy (0.11 eV) due to the small energy separations between the lowest-energy bands. More detailed discussions about tBLG with $\theta \leq 2^\circ$ are given in the Supplemental Material [44]. Future studies with more comprehensive experiments of small-twist-angle tBLG and more precise determinations of twist angles are needed to explore further tBLG plasmons in the non-Dirac regime.

By combining the state-of-the-art s-SNOM technique with rigorous numerical modeling, we performed a systematic nano-infrared imaging study of tBLG single crystals with various

twist angles. In the Dirac linear regime, we found that tBLG support infrared plasmons with parameters that vary systematically with the twist angle between the two graphene planes. The underlining physics behind the observed twist angle dependence is the Fermi velocity renormalization, which is originated from the interlayer electronic coupling. Our study establishes tBLG as a unique platform where the Fermi velocity, the fundamentally important parameter of Dirac fermions, has become an adjustable variable in nano-optical and plasmonic studies of Dirac materials.

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Figure Captions

FIG. 1. (a) Illustration of the nano-infrared imaging experiment of a tBLG/SLG single crystal. The solid and dashed arrows mark the direction of the incident laser beam and back-scattered photons, respectively. (b) Sketch of the crystal structure of tBLG revealing moiré periodic pattern. The double-sided arrow marks the moiré period. (c) Calculated band structure of tBLG with a twist angle of 5° with the continuum model [25]. Here the momentum unit ΔK equals to the separation between the two Dirac points (K_1 and K_2) in the momentum space. (d) Optical image of representative tBLG/SLG single-crystal samples. The scale bar represents 5 μm .

FIG. 2. (a) Sketch of the sample geometry indicating two adjacent tBLG grains with different twist angles with respect to SLG. (b) and (c) The near-field images plotting scattering amplitude (s) and phase (ψ), respectively. In both images, the amplitude or phase signal is normalized to that of SLG. The laser energy is set to be at $E = 0.11$ eV. The scale bars represent 3 μm .

FIG. 3. (a)-(e) High-resolution near-field amplitude images of the five small regions ('P1' – 'P5') marked in Fig. S1 (squares), respectively. The white dashed lines in the images mark the SLG edge and the tBLG/SLG boundaries. The scale bars represent 400 nm. (f)-(j), Experimental (grey

solid) and modeled (red dashed) amplitude profiles taken along the blue dashed lines in the corresponding near-field images above. The blue arrows in (g) and (h) mark the size of λ_p^{tBLG} that is twice the fringe period. The vertical dashed lines mark the boundaries between SLG and tBLG.

FIG. 4. (a) The λ_p^{tBLG} data points extracted by modeling the fringe profiles in Fig. 3. Inset plots the calculated $v_F^{\text{tBLG}}(\theta)$ considering different t . (b) The γ_p^{tBLG} data points extracted by modeling the fringe profiles in Fig. 3. The red curves in (a) and (b) are used for calculations of the amplitude and phase signals in (c) and (d). The blue arrows in (a) and (b) mark the values of λ_p^{SLG} and γ_p^{SLG} , respectively. (c) The θ -dependent near-field amplitude from both experiment (squares) and modeling (red curve). (d) The θ -dependent near-field phase from both experiment (squares) and modeling (red curve). Both the amplitude (c) and phase (d) of tBLG are normalized to those of SLG. The vertical dashed lines in (c) and (d) mark $\theta = 3^\circ$.

Figure 1

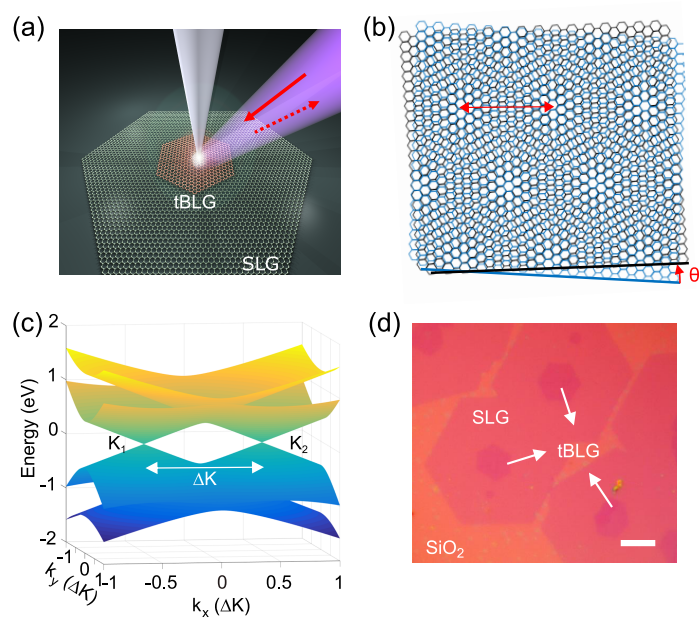


Figure 2

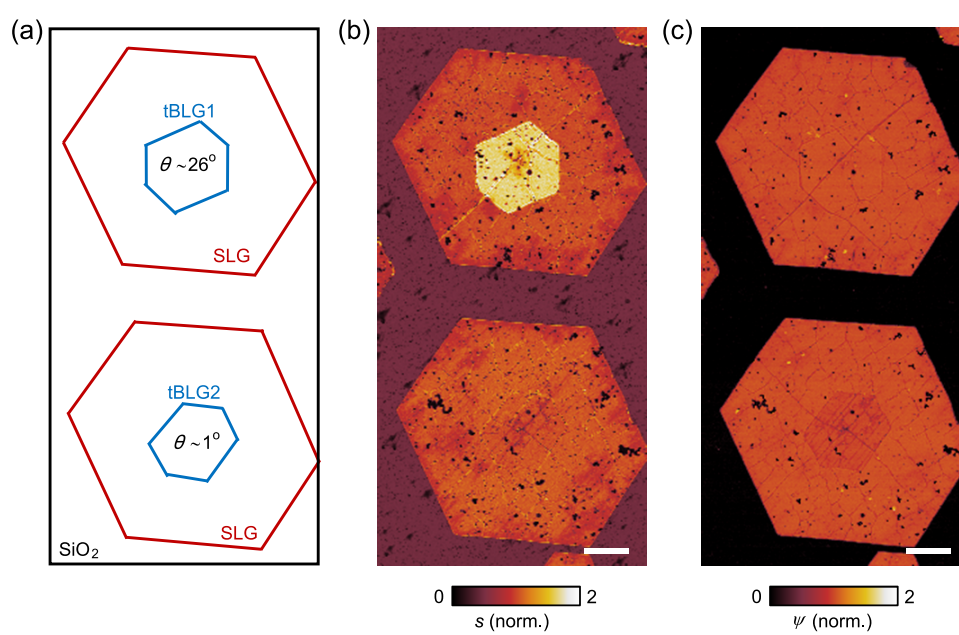


Figure 3

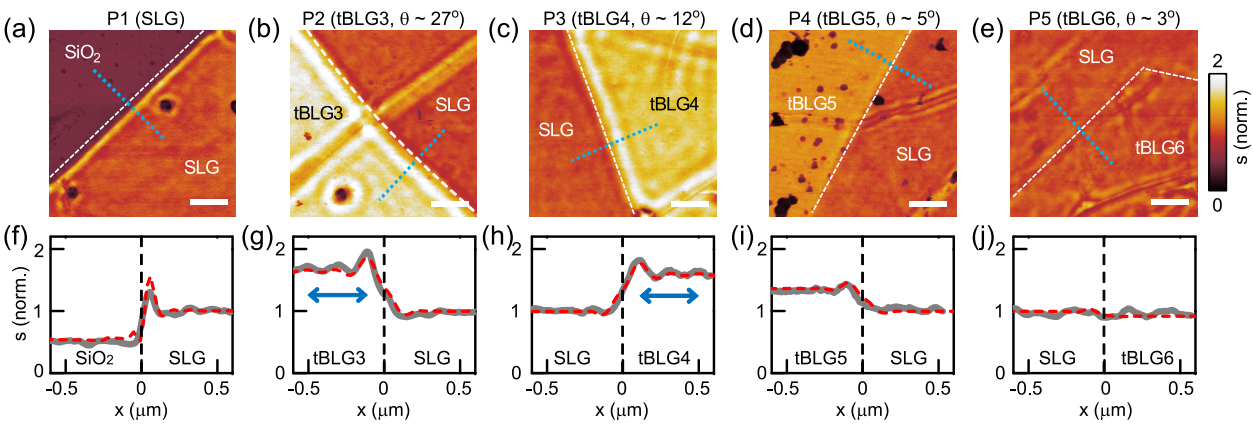


Figure 4

